

FOD8160

High Noise Immunity, 3.3 V / 5 V, 10 Mbit/sec, Logic Gate Optocoupler in Wide-Body SOP 5-Pin

Features

- Optoplanar® packaging technology allows more than 10 mm creepage and clearance distance, and 0.5 mm insulation distance to achieve reliable and high voltage insulation
- High noise immunity characterized by common-mode transient immunity (CMTI)
 - 20 kV/μs Minimum CMTI
- Specifications guaranteed over 3 V to 5.5 V supply voltage and -40°C to 100°C extended industrial temperature range
- High speed, 10 Mbit/sec Data Rate (NRZ)
- Safety and regulatory approvals
 - UL1577, 5,000 VAC_{RMS} for 1 minute
 - DIN-EN/IEC60747-5-5, 1,414 V peak working insulation voltage (pending approval)

Applications

- Isolating intelligent power module
- Isolating industrial communication interface

Related Resources

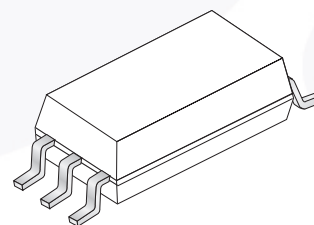
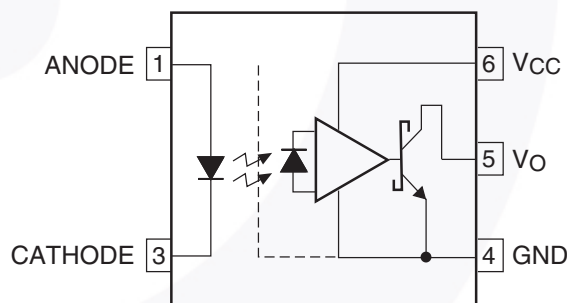
- www.fairchildsemi.com/products/opto/
- www.fairchildsemi.com/pf/FO/FODM8061.html
- www.fairchildsemi.com/pf/FO/FODM611.html

Description

The FOD8160 is a 3.3 V / 5 V high-speed logic gate optocoupler with open collector output, which supports isolated communications to allow digital signals to communicate between systems without conducting ground loops or hazardous voltages. It utilizes Fairchild's proprietary Optoplanar® coplanar packaging technology and optimized IC design to achieve high noise immunity, characterized by high common-mode rejection specifications.

The FOD8160, packaged in a wide-body SOP 5-Pin package, consists of an aluminium gallium arsenide (AlGaAs) LED and an integrated high-speed photodetector. The output of the detector IC is an open collector Schottky-clamped transistor. The electrical and switching characteristics are guaranteed over the extended industrial temperature range of -40°C to 100°C and a V_{CC} range of 3 V to 5.5 V.

Functional Schematic



Truth Table

LED	Output
Off	HIGH
On	LOW

Pin Definitions

Pin #	Name	Description
1	Anode	Anode
3	Cathode	Cathode
4	GND	Output Ground
5	V _O	Output Voltage
6	V _{CC}	Output Supply Voltage

Pin Configuration



Safety and Insulation Ratings

As per DIN EN/IEC60747-5-5 (pending approval), this optocoupler is suitable for “safe electrical insulation” only within the safety limit data below. Compliance with the safety ratings shall be ensured by means of protective circuits.

Symbol	Parameter	Min.	Typ.	Max.	Unit
	Installation Classifications per DIN VDE 0110/1.89 Table 1				
	For Rated Mains Voltage < 150 Vrms		I–IV		
	For Rated Mains Voltage < 300 Vrms		I–IV		
	For Rated Mains Voltage < 450 Vrms		I–IV		
	For Rated Mains Voltage < 600 Vrms		I–IV		
	Climatic Classification		40/100/21		
	Pollution Degree (DIN VDE 0110/1.89)		2		
CTI	Comparative Tracking Index	175			
V_{PR}	Input to Output Test Voltage, Method b, $V_{IORM} \times 1.875 = V_{PR}$, 100% Production Test with $t_m = 1$ s, Partial Discharge < 5 pC	2,651			V_{peak}
	Input to Output Test Voltage, Method a, $V_{IORM} \times 1.5 = V_{PR}$, Type and Sample Test with $t_m = 60$ s, Partial Discharge < 5 pC	2,121			V_{peak}
V_{IORM}	Maximum Working Insulation Voltage	1,414			V_{peak}
V_{IOTM}	Highest Allowable Over Voltage	8,000			V_{peak}
	External Creepage	10.0			mm
	External Clearance	10.0			mm
	Insulation Thickness	0.5			mm
T_S	Safety Limit Values – Maximum Values Allowed in the Event of a Failure				
	Case Temperature	150			°C
$I_{S,INPUT}$	Input Current	200			mA
$P_{S,OUTPUT}$	Output Power	600			mW
R_{IO}	Insulation Resistance at T_S , $V_{IO} = 500$ V	10^9			Ω

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. $T_A = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	Value	Units
T_{STG}	Storage Temperature	-40 to +125	$^\circ\text{C}$
T_{OPR}	Operating Temperature	-40 to +100	$^\circ\text{C}$
T_J	Junction Temperature	-40 to +125	$^\circ\text{C}$
T_{SOL}	Lead Solder Temperature (Refer to Reflow Temperature Profile on page 12)	260 for 10 sec	$^\circ\text{C}$
Input Characteristics			
I_F	Average Forward Input Current	25	mA
V_R	Reverse Input Voltage	5.0	V
PD_I	Input Power Dissipation ⁽¹⁾	45	mW
Output Characteristics			
V_{CC}	Supply Voltage	0 to 7.0	V
V_O	Output Voltage	-0.5 to $V_{CC} + 0.5$	V
I_O	Average Output Current	50	mA
PD_O	Output Power Dissipation ⁽¹⁾	85	mW

Note:

1. No derating required up to 100°C .

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Unit
T_A	Ambient Operating Temperature	-40	+100	$^\circ\text{C}$
V_{CC}	Supply Voltages ⁽²⁾	3.0	5.5	V
V_{FL}	Logic Low Input Voltage	0	0.8	V
I_{FL}	Logic Low Input Current		250	μA
I_{FH}	Logic High Input Current	6.0	15	mA
N	Fan Out (at $R_L = 1\text{ k}\Omega$)		5	TTL loads
R_L	Output Pull-up Resistor	330	4,000	Ω

Note:

2. 0.1 μF bypass capacitor must be connected between pins 4 and 6.

Isolation Characteristics

Apply over all recommended conditions; typical value is measured at $T_A = 25^\circ\text{C}$.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V_{ISO}	Input-Output Isolation Voltage	$T_A = 25^\circ\text{C}$, R.H. < 50%, $t = 1.0$ min, $I_{\text{I-O}} \leq 20 \mu\text{A}^{(3)(4)}$	5,000			VAC_{RMS}
R_{ISO}	Isolation Resistance	$V_{\text{I-O}} = 500 \text{ V}^{(3)}$		10^{11}		Ω
C_{ISO}	Isolation Capacitance	$V_{\text{I-O}} = 0 \text{ V}$, frequency = $1.0 \text{ MHz}^{(3)}$		1.0		pF

Notes:

- Device is considered a two-terminal device: pins 1 and 3 are shorted together and pins 4, 5, and 6 are shorted together.
- 5,000 VAC_{RMS} for 1-minute duration is equivalent to 6,000 VAC_{RMS} for 1-second duration.

Electrical Characteristics

Apply over all recommended conditions; $T_A = -40^\circ\text{C}$ to $+100^\circ\text{C}$, $3.0 \text{ V} \leq V_{\text{CC}} \leq 5.5 \text{ V}$; unless otherwise specified. Typical value is measured at $T_A = 25^\circ\text{C}$ and $V_{\text{CC}} = 3.3 \text{ V}$ or $V_{\text{CC}} = 5 \text{ V}$.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units	Figure
INPUT CHARACTERISTICS							
V_F	Forward Voltage	$I_F = 10 \text{ mA}$	1.05	1.45	1.80	V	1
$\Delta(V_F / T_A)$	Temperature Coefficient of Forward Voltage			-1.8		mV/ $^\circ\text{C}$	
BV_R	Input Reverse Breakdown Voltage	$I_R = 10 \mu\text{A}$	5.0			V	
I_{FHL}	Threshold Input Current	$V_O = 0.6 \text{ V}$, $I_{\text{OL}}(\text{sink}) = 13 \text{ mA}$		2.5	6.0	mA	2
OUTPUT CHARACTERISTICS							
V_{OL}	Logic Low Output Voltage	$I_F = \text{rated } I_{\text{FHL}}$, $I_{\text{OL}}(\text{sink}) = 13 \text{ mA}$		0.4	0.6	V	3
I_{OH}	Logic High Output Current	$I_F = 250 \mu\text{A}$, $V_O = 3.3 \text{ V}$		8.0	50.0	μA	4
		$I_F = 250 \mu\text{A}$, $V_O = 5.0 \text{ V}$		3.0	40.0	μA	4
I_{CCL}	Logic Low Output Supply Current	$I_F = 10 \text{ mA}$, $V_{\text{CC}} = 3.3 \text{ V}$		5.3	8.5	mA	5, 7
		$I_F = 10 \text{ mA}$, $V_{\text{CC}} = 5.0 \text{ V}$		7.1	10.0	mA	5, 7
I_{CCH}	Logic High Output Supply Current	$I_F = 0 \text{ mA}$, $V_{\text{CC}} = 3.3 \text{ V}$		3.5	7.0	mA	6, 7
		$I_F = 0 \text{ mA}$, $V_{\text{CC}} = 5.0 \text{ V}$		5.3	9.0	mA	6, 7

Switching Characteristics

Apply over all recommended conditions; $T_A = -40^\circ\text{C}$ to $+100^\circ\text{C}$, $V_{CC} = 3.3\text{ V}$, $I_F = 6.0\text{ mA}$; unless otherwise specified. Typical value is measured at $T_A = 25^\circ\text{C}$ and $V_{CC} = 3.3\text{ V}$.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units	Figure
Data Rate		$R_L = 350\ \Omega$			10	Mbit/sec	
t_{PHL}	Propagation Delay to Logic Low Output	$R_L = 350\ \Omega$, $C_L = 15\text{ pF}$		40	80	ns	8, 9, 13
t_{PLH}	Propagation Delay to Logic High Output	$R_L = 350\ \Omega$, $C_L = 15\text{ pF}$		50	90	ns	8, 9, 13
PWD	Pulse Width Distortion, $ t_{PHL} - t_{PLH} $	$R_L = 350\ \Omega$, $C_L = 15\text{ pF}$		10	35	ns	10, 11, 13
t_{PSK}	Propagation Delay Skew	$R_L = 350\ \Omega$, $C_L = 15\text{ pF}$ ⁽⁵⁾			40	ns	
t_R	Output Rise Time (10% to 90%)	$R_L = 350\ \Omega$, $C_L = 15\text{ pF}$		20		ns	12, 13
t_F	Output Fall Time (90% to 10%)	$R_L = 350\ \Omega$, $C_L = 15\text{ pF}$		10		ns	12, 13
$ CM_H $	Common-Mode Transient Immunity at Output High	$I_F = 0\text{ mA}$, $V_O > 2\text{ V}$, $V_{CM} = 1,000\text{ V}^{(6)}$	20	40		kV/ μs	14
$ CM_L $	Common-Mode Transient Immunity at Output Low	$I_F = 6.0\text{ mA}$, $V_O < 0.8\text{ V}$, $V_{CM} = 1,000\text{ V}^{(6)}$	20	40		kV/ μs	14

Apply over all recommended conditions; $T_A = -40^\circ\text{C}$ to $+100^\circ\text{C}$, $V_{CC} = 5\text{ V}$, $I_F = 6.0\text{ mA}$; unless otherwise specified. Typical value is measured at $T_A = 25^\circ\text{C}$ and $V_{CC} = 5\text{ V}$.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units	Figure
Data Rate		$R_L = 350\ \Omega$			10	Mbit/sec	
t_{PHL}	Propagation Delay to Logic Low Output	$R_L = 350\ \Omega$, $C_L = 15\text{ pF}$		37	80	ns	8, 9, 13
t_{PLH}	Propagation Delay to Logic High Output	$R_L = 350\ \Omega$, $C_L = 15\text{ pF}$		41	90	ns	8, 9, 13
PWD	Pulse Width Distortion, $ t_{PHL} - t_{PLH} $	$R_L = 350\ \Omega$, $C_L = 15\text{ pF}$		4	25	ns	10, 11, 13
t_{PSK}	Propagation Delay Skew	$R_L = 350\ \Omega$, $C_L = 15\text{ pF}^{(5)}$			40	ns	
t_R	Output Rise Time (10% to 90%)	$R_L = 350\ \Omega$, $C_L = 15\text{ pF}$		22		ns	12, 13
t_F	Output Fall Time (90% to 10%)	$R_L = 350\ \Omega$, $C_L = 15\text{ pF}$		9		ns	12, 13
$ CM_H $	Common-Mode Transient Immunity at Output High	$I_F = 0\text{ mA}$, $V_O > 2\text{ V}$, $V_{CM} = 1,000\text{ V}^{(6)}$	20	40		kV/ μs	14
$ CM_L $	Common-Mode Transient Immunity at Output Low	$I_F = 6.0\text{ mA}$, $V_O < 0.8\text{ V}$, $V_{CM} = 1,000\text{ V}^{(6)}$	20	40		kV/ μs	14

Notes:

5. t_{PSK} is equal to the magnitude of the worst-case difference in t_{PHL} and/or t_{PLH} between any two units from the same manufacturing date code that are operated at same case temperature ($\pm 5^{\circ}\text{C}$), at same operating conditions, with equal loads ($R_L = 350\ \Omega$, $C_L = 15\ \text{pF}$), and with an input rise time less than 5 ns.
6. Common-mode transient immunity at output HIGH is the maximum tolerable positive dV_{cm}/dt on the leading edge of the common-mode impulse signal, V_{CM} , to assure that the output remains HIGH. Common-mode transient immunity at output LOW is the maximum tolerable negative dV_{cm}/dt on the trailing edge of the common pulse signal, V_{CM} , to assure that the output remains LOW.

Typical Performance Characteristics

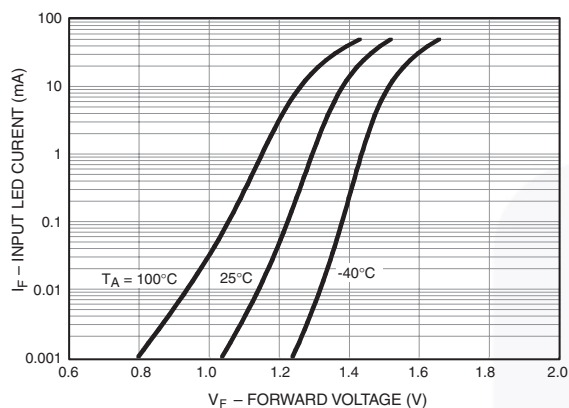


Figure 1. Input LED Current (I_F) vs. Forward Voltage (V_F)

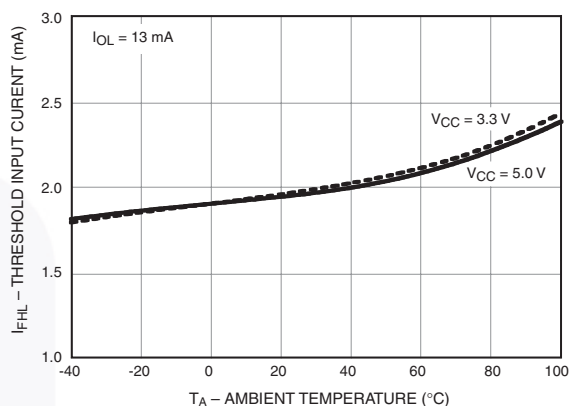


Figure 2. Threshold Input Current (I_{FHL}) vs. Ambient Temperature

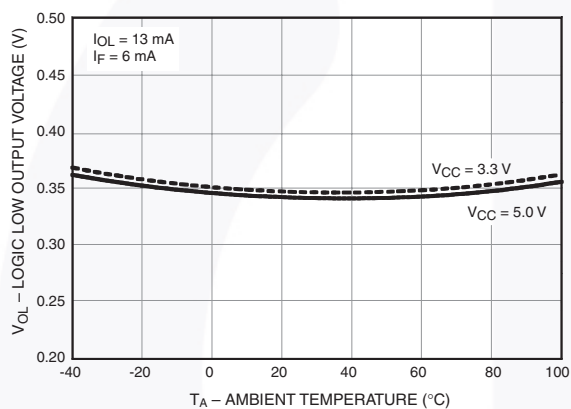


Figure 3. Logic Low Output Voltage (V_{OL}) vs. Ambient Temperature

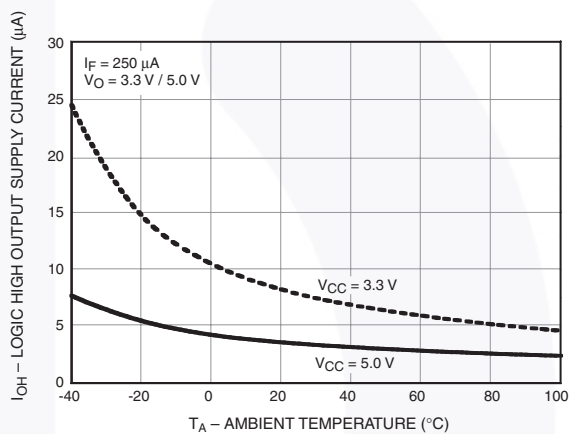


Figure 4. Logic High Output Current (I_{OH}) vs. Ambient Temperature

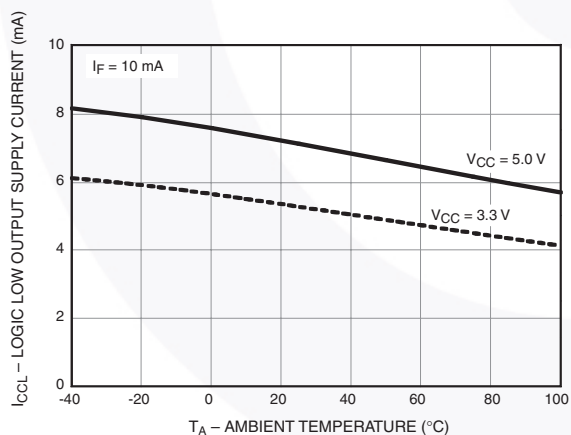


Figure 5. Logic Low Output Supply Current (I_{CCL}) vs. Ambient Temperature

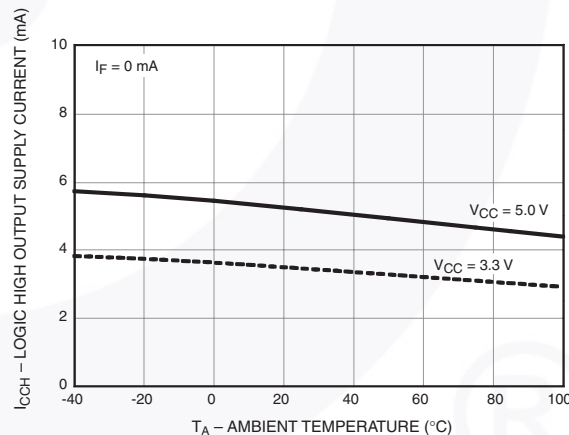


Figure 6. Logic High Output Supply Current (I_{CCH}) vs. Ambient Temperature

Typical Performance Characteristics (Continued)

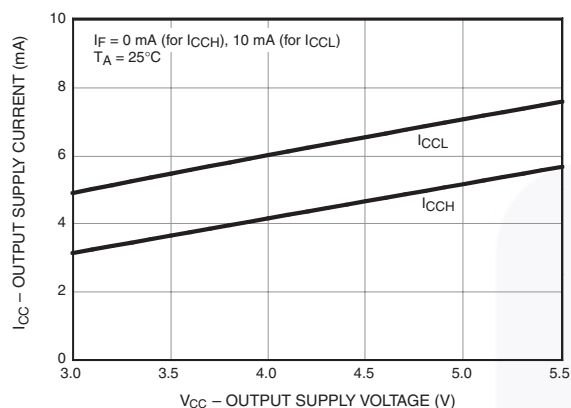
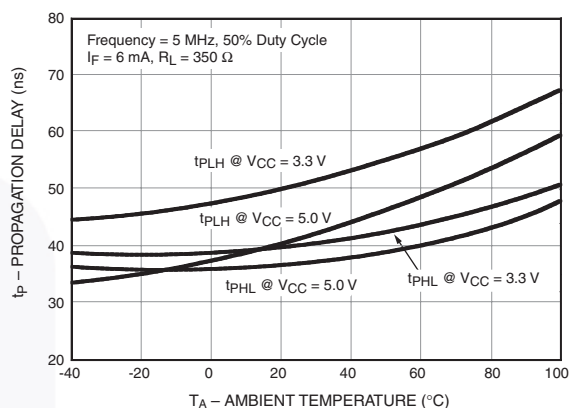
Figure 7. Output Supply Current (I_{CC}) vs. Output Supply Voltage (V_{CC})

Figure 8. Propagation Delay vs. Ambient Temperature

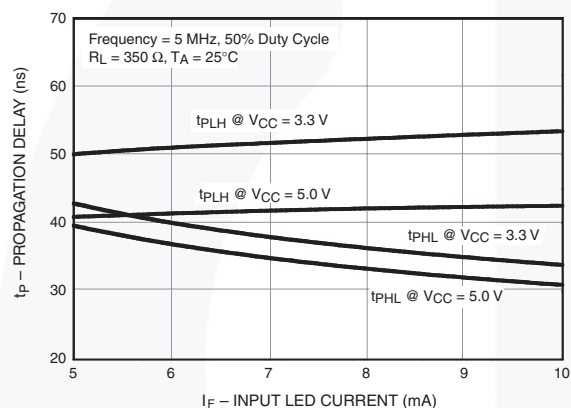
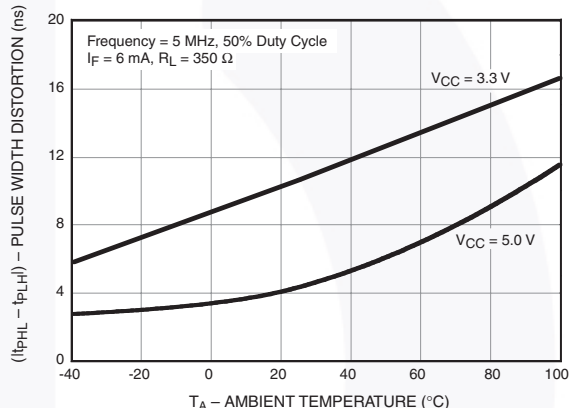
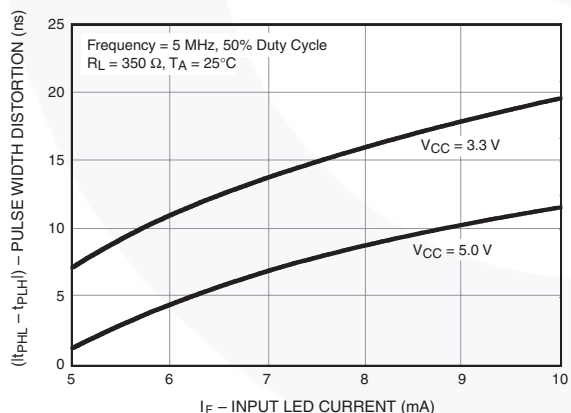
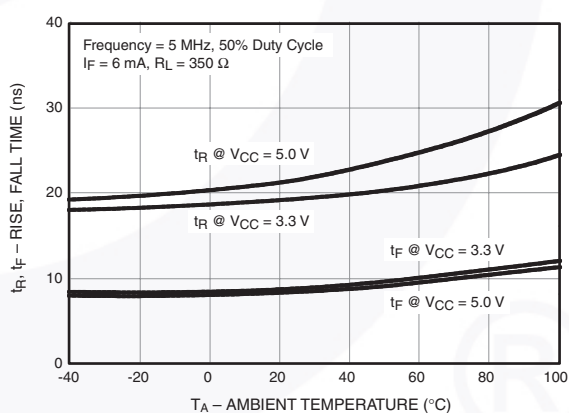
Figure 9. Propagation Delay vs. Input LED Current (I_F)

Figure 10. Pulse Width Distortion vs. Ambient Temperature

Figure 11. Pulse Width Distortion vs. Input LED Current (I_F)Figure 12. Rise Time (t_R) and Fall Time (t_F) vs. Ambient Temperature

Test Circuit

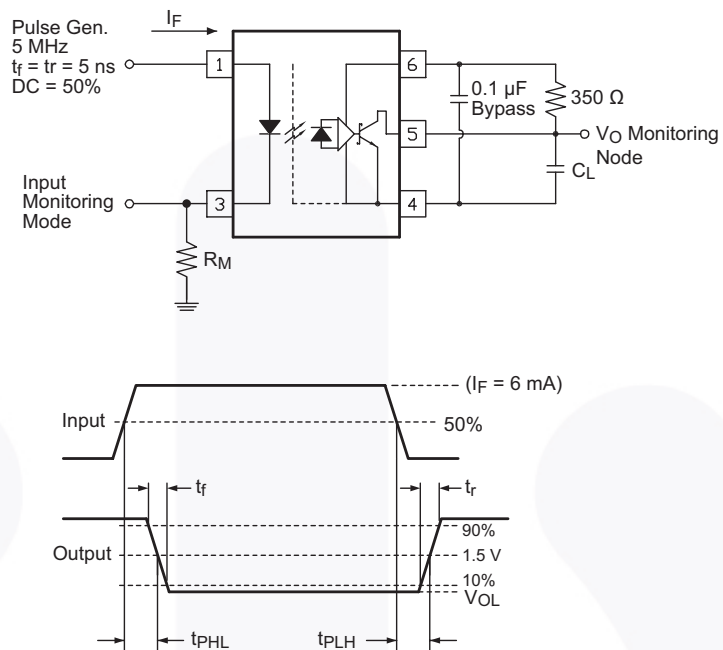


Figure 13. Test Circuit for Propagation Delay, Rise Time, and Fall Time

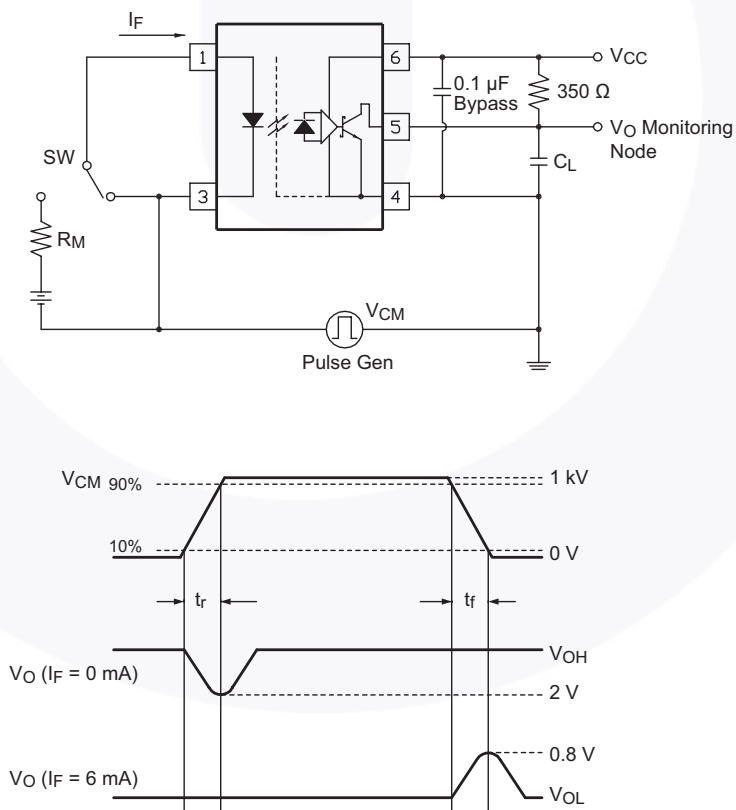


Figure 14. Test Circuit for Instantaneous Common-Mode Rejection Voltage

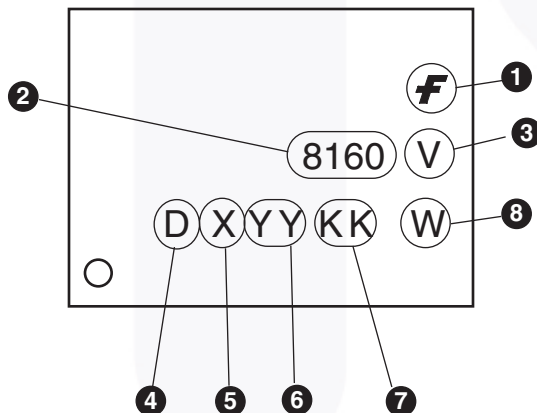
Ordering Information

Part Number	Package	Packing Method
FOD8160	Wide Body SOP 5-Pin	Tube (100 units per tube)
FOD8160R2	Wide Body SOP 5-Pin	Tape and Reel (1,000 units per reel)
FOD8160V (Preliminary)	Wide Body SOP 5-Pin, DIN EN/IEC60747-5-5 Option (Pending Approval)	Tube (100 units per tube)
FOD8160R2V (Preliminary)	Wide Body SOP 5-Pin, DIN EN/ IEC60747-5-5 Option (Pending Approval)	Tape and Reel (1,000 units per reel)



All packages are lead free per JEDEC: J-STD-020B standard.

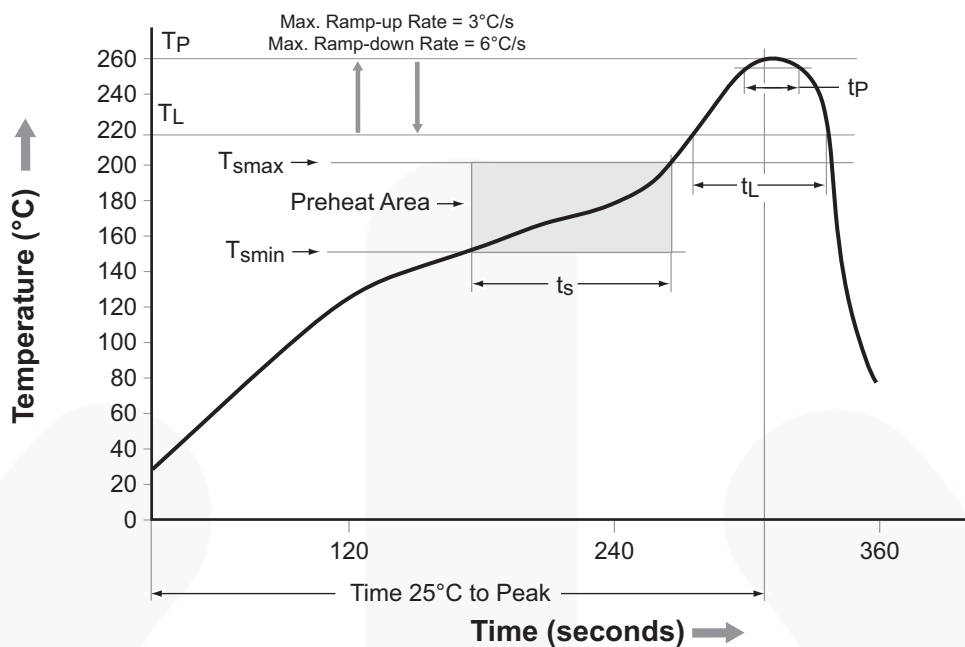
Marking Information



Definitions

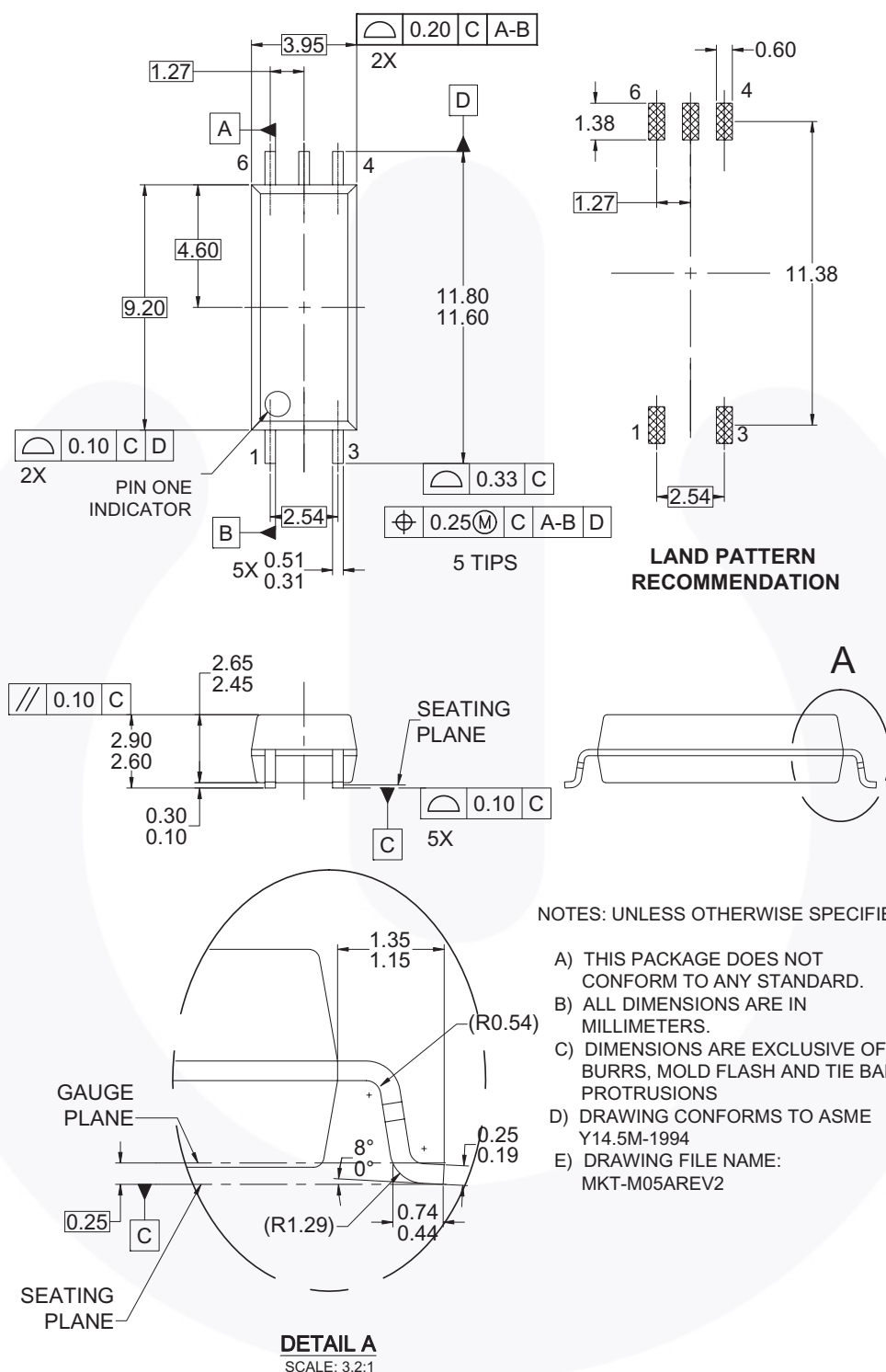
1	Fairchild logo
2	Device number, e.g., '8160' for FOD8160
3	DIN EN/IEC60747-5-5 option (only appears on component ordered with this option)
4	Plant code, e.g., 'D'
5	Last-digit year code, e.g., 'D' for 2013
6	Two-digit work week ranging from '01' to '53'
7	Lot-traceability code
8	Package assembly code, W

Reflow Profile



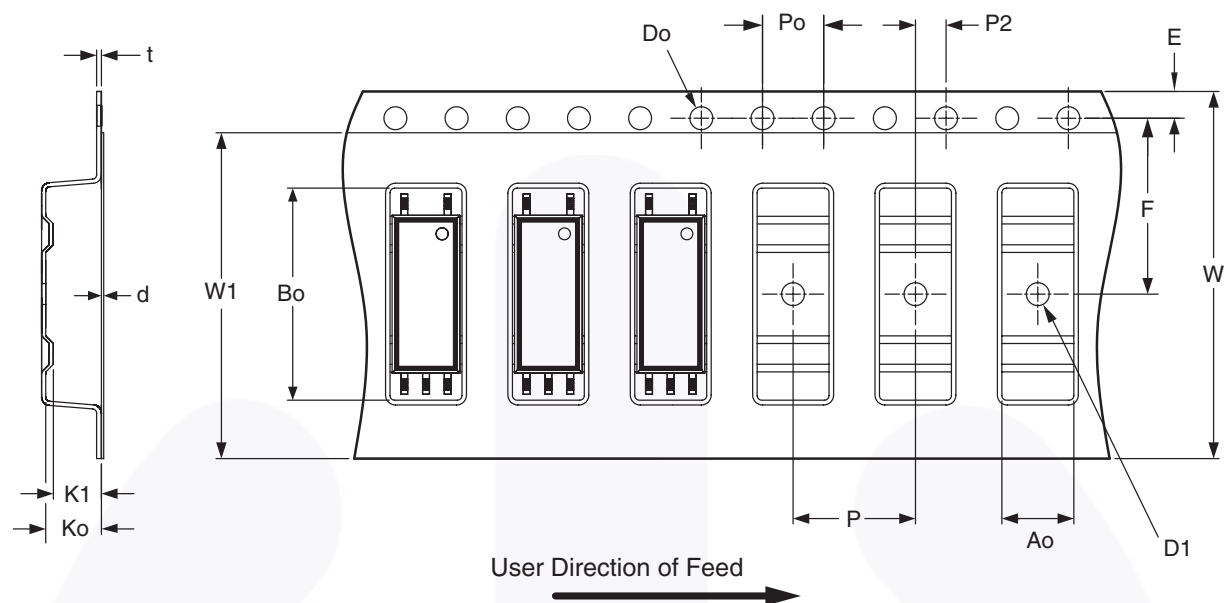
Profile Feature	Pb-Free Assembly Profile
Temperature Minimum (T_{smin})	150°C
Temperature Maximum (T_{smax})	200°C
Time (t_s) from (T_{smin} to T_{smax})	60–120 Seconds
Ramp-Up Rate (t_L to t_P)	3°C/Second max.
Liquidous Temperature (T_L)	217°C
Time (t_L) Maintained Above (T_L)	60–150 Seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t_P) within 5°C of 260°C	30 Seconds
Ramp-Down Rate (T_P to T_L)	6°C/Second max.
Time 25°C to Peak Temperature	8 Minutes max.

Package Dimensions



Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings:
<http://www.fairchildsemi.com/packaging/>

Carrier Tape Specification (SOIC-5L OPTO R2 & R2V Option)

Symbol	Description	Dimension in mm
W	Tape Width	24.00 +0.20 / -0.10
t	Tape Thickness	0.30 ±0.05
Po	Sprocket Hole Pitch	4.00 ±0.20
Do	Sprocket Hole Diameter	1.50 +0.10 / -0.00
D1	Pocket Hole Diameter	1.50 +0.25 / -0.00
E	Sprocket Hole Location	1.75 ±0.10
F	Pocket Location	11.50 ±0.10
P2	Pocket Pitch	2.00 ±0.10
P	Pocket Pitch	8.00 ±0.10
Ao	Pocket Dimension	4.50 ±0.10
Bo	Pocket Dimension	12.00 ±0.10
Ko	Pocket Dimension	3.35 ±0.10
K1	Pocket Dimension	2.85 ±0.10
W1	Cover Tape Width	21.30 ±0.10
d	Cover Tape Thickness	0.05 ±0.01
	Max Component Rotation or Tilt	10°



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AX-CAP™*	Global Power Resource™	Programmable Active Droop™	TinyBoost™
BitSiC™	GreenBridge™	QFET®	TinyBuck™
Build it Now™	Green FPS™	QS™	TinyCalc™
CorePLUS™	Green FPS™ e-Series™	Quiet Series™	TinyLogic®
CorePOWER™	Gmax™	RapidConfigure™	TINYOPTO™
CROSSVOLT™	GTO™	 Saving our world, 1mW/W/kW at a time™	TinyPower™
CTL™	IntelliMAX™	SignalWise™	TinyPWM™
Current Transfer Logic™	ISOPLANAR™	SmartMax™	TinyWire™
DEUXPEED®	Making Small Speakers Sound Louder and Better™	SMART START™	TranSiC™
Dual Cool™	MegaBuck™	Solutions for Your Success™	TriFault Detect™
EcoSPARK®	MICROCOUPLER™	SPM®	TRUECURRENT®*
EfficientMax™	MicroFET™	STEALTH™	µSerDes™
ESBC™	MicroPak™	SuperFET®	 SerDes™
 Fairchild®	MicroPak2™	SuperSOT™-3	UHC®
Fairchild Semiconductor®	MillerDrive™	SuperSOT™-6	Ultra FRFET™
FACT Quiet Series™	MotionMax™	SuperSOT™-8	UnifET™
FACT®	mWSaver™	SupreMOS®	VCX™
FAST®	OptoHiT™	SyncFET™	VisualMax™
FastvCore™	OPTOLOGIC®	Sync-Lock™	VoltagePlus™
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2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

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